# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## **DSEP60-12A**

$V_{\text{RRM}}$	=	1200 V
I <sub>FAV</sub>	=	60 A
t <sub>rr</sub>	=	40 ns

High Performance Fast Recovery Diode Low Loss and Soft Recovery Single Diode

Part number

**DSEP60-12A** 



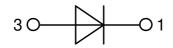
Package: TO-247

RoHS compliant

• Industry standard outline

• Epoxy meets UL 94V-0

Backside: cathode



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
- Power dissipation within the diode
- Turn-on loss in the commutating switch

#### **Applications:**

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode · Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Terms Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office. Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747and per semiconductor unless otherwise specified

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## DSEP60-12A

Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse blocki	ng voltage	$T_{VJ} = 25^{\circ}C$			1200	V
V <sub>RRM</sub>	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			1200	V
I <sub>R</sub>	reverse current, drain current	V <sub>R</sub> = 1200 V	$T_{VJ} = 25^{\circ}C$			650	μA
		$V_{R} = 1200 V$	$T_{vJ} = 150^{\circ}C$			2.5	mA
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 60 A	$T_{vJ} = 25^{\circ}C$			2.66	V
		I <sub>F</sub> = 120 A				3.18	V
		$I_{\rm F} = 60  {\rm A}$	T <sub>vJ</sub> = 150°C			1.81	V
		$I_{F} = 120 \text{ A}$				2.40	V
FAV	average forward current	T <sub>c</sub> = 115°C	$T_{vJ} = 175 ^{\circ}C$			60	Α
		rectangular d = 0.5					
V <sub>F0</sub>	threshold voltage		$T_{vJ} = 175^{\circ}C$			1.08	V
r <sub>F</sub>	slope resistance } for power lo	oss calculation only				9.4	mΩ
$\mathbf{R}_{thJC}$	thermal resistance junction to case	e				0.45	K/W
$\mathbf{R}_{thCH}$	thermal resistance case to heatsir	nk			0.25		K/W
P <sub>tot</sub>	total power dissipation		$T_c = 25^{\circ}C$			330	W
I <sub>FSM</sub>	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_{R} = 0 V$	$T_{VJ} = 45^{\circ}C$			500	Α
C	junction capacitance	$V_{R} = 600 V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		30		pF
I <sub>RM</sub>	max. reverse recovery current	<b>)</b>	$T_{vJ} = 25 °C$		13		Α
		$I_{\rm F} = 60  \text{A};  V_{\rm R} = 600  \text{V}$	$T_{vJ} = 100 ^{\circ}C$		20		Α
t <sub>rr</sub>	reverse recovery time	I <sub>F</sub> = 60 A; V <sub>R</sub> = 600 V -di <sub>F</sub> /dt = 200 A/μs	$T_{VJ} = 25 ^{\circ}C$		80		ns
		,	$T_{vJ} = 100 ^{\circ}\text{C}$		220		ns

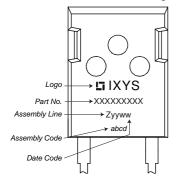
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## **DSEP60-12A**

Package TO-247			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per terminal			70	Α
T <sub>vj</sub>	virtual junction temperature		-55		175	°C
T <sub>op</sub>	operation temperature		-55		150	°C
<b>T</b> <sub>stg</sub>	storage temperature		-55		150	°C
Weight				6		g
M <sub>D</sub>	mounting torque		0.8		1.2	Nm
F <sub>c</sub>	mounting force with clip		20		120	Ν

**Product Marking** 



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSEP60-12A	DSEP60-12A	Tube	30	477133

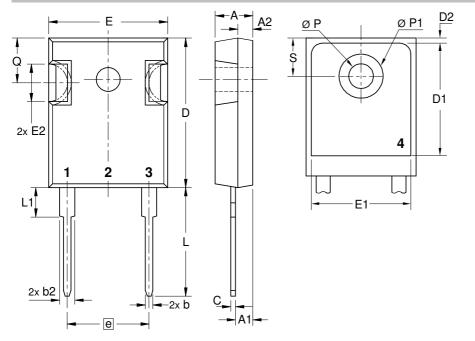
Similar Part	Package	Voltage class
DSEP60-12B	TO-247AD (2)	1200
DSEP60-12AR	ISOPLUS247 (2)	1200
DHG60I1200HA	TO-247AD (2)	1200

Equivalent Circuits for Simulation		* on die level	$T_{VJ} = 175 ^{\circ}C$	
	) <b>□ R</b> ₀	Fast Diode		
V <sub>0 max</sub>	threshold voltage	1.08		V
$\mathbf{R}_{0 \max}$	slope resistance *	6.8		mΩ

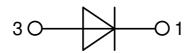
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### Outlines TO-247



Sym.	Inches		Millimeter		
	min.	max.	min.	max.	
A	0.185	0.209	4.70	5.30	
A1	0.087	0.102	2.21	2.59	
A2	0.059	0.098	1.50	2.49	
D	0.819	0.845	20.79	21.45	
E	0.610	0.640	15.48	16.24	
E2	0.170	0.216	4.31	5.48	
е	0.430	BSC	10.92	BSC	
L	0.780	0.800	19.80	20.30	
L1	-	0.177	-	4.49	
ØР	0.140	0.144	3.55	3.65	
Q	0.212	0.244	5.38	6.19	
S	0.242	BSC	6.14	BSC	
b	0.039	0.055	0.99	1.40	
b2	0.065	0.094	1.65	2.39	
b4	0.102	0.135	2.59	3.43	
с	0.015	0.035	0.38	0.89	
D1	0.515	-	13.07	-	
D2	0.020	0.053	0.51	1.35	
E1	0.530	-	13.45	-	
ØP1	-	0.29	-	7.39	



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## **DSEP60-12A**

### **Fast Diode**

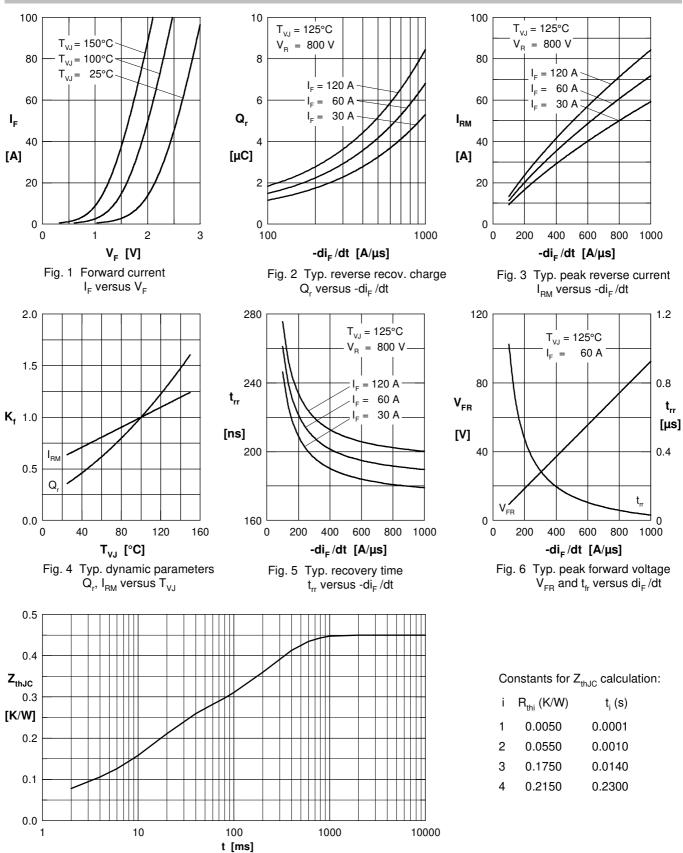


Fig. 7 Transient thermal resistance junction to case

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